

**UltraCMOS® RF Digital Step Attenuator, 7-bit, 31.75 dB with Optional V<sub>SS</sub>EXT Bypass Mode 9 kHz - 8 GHz**

**Features**

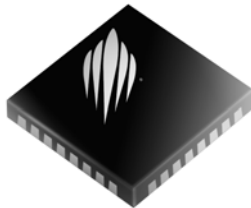
- HaRP™ technology enhanced
- Safe attenuation state transitions
- Attenuation options: covers a 31.75 dB range in 0.25 dB, 0.5 dB, or 1.0 dB steps
  - 0.25 dB monotonicity for ≤ 6 GHz
  - 0.50 dB monotonicity for ≤ 7 GHz
  - 1.00 dB monotonicity for ≤ 8 GHz
- High power handling @ 8 GHz in 50Ω
  - 28 dBm CW
  - 31 dBm instantaneous power
- High linearity
  - IIP3 of 61 dBm
- 1.8V/3.3V control logic
- Programming modes
  - Direct parallel
  - Latched parallel
  - Serial
  - Serial Addressable
- High-attenuation state @ power-up (PUP)
- ESD performance
  - 1.5kV HBM on all pins

**Product Description**

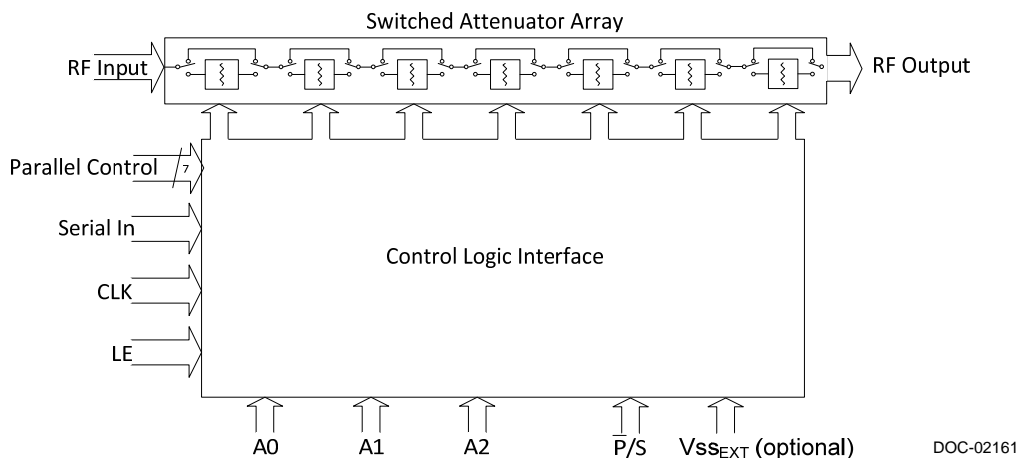
The PE43704 is a HaRP™ technology-enhanced, high linearity, 7-bit 50Ω RF Digital Step Attenuator (DSA). It offers maximum power handling of 28 dBm up to 8 GHz and covers a 31.75 dB attenuation range in 0.25 dB, 0.5 dB, or 1.0 dB steps. The PE43704 is a pin-compatible version of PE43703. It provides multiple CMOS control interfaces and an optional V<sub>SS</sub>EXT bypass mode to improve spurious performance. It maintains high attenuation accuracy over frequency and temperature and exhibits very low insertion loss and low power consumption. No blocking capacitors are required if DC voltage is not present on the RF ports.

The PE43704 is manufactured on Peregrine's UltraCMOS® process, a patented variation of silicon-on-insulator (SOI) technology on a sapphire substrate, offering the performance of GaAs with the economy and integration of conventional CMOS.

**Figure 1. Package Type**  
32-lead 5x5 QFN



**Figure 2. Functional Diagram**



DOC-02161

**Table 1. Electrical Specifications: 0.25 dB steps @ +25°C,  $V_{DD} = 2.3V$  to  $5.5V$ ,  $V_{SS_{EXT}} = 0V$  or  $V_{DD} = 3.4V$  to  $5.5V$ ,  $V_{SS_{EXT}} = -3.4V$  ( $Z_S = Z_L = 50\Omega$ ) unless otherwise noted**

Parameter	Condition	Frequency	Min	Typ	Max	Unit	
Operating frequency			9 kHz		6000 MHz	As shown	
Attenuation range	0.25 dB Step			0 – 31.75		dB	
Insertion loss		9 kHz – 2 GHz		1.3	1.4	dB	
		2 GHz – 4 GHz		1.7	1.9	dB	
		4 GHz – 6 GHz		2.4	2.7	dB	
Attenuation error	0 dB – 15.75 dB Attenuation settings	9 KHz ≤ 4 GHz			+ (0.15 + 3% of Attenuation Setting) - (0.1 + 1% of Attenuation Setting)	dB	
					+ (0.15 + 5% of Attenuation Setting) - 0.15	dB	
	16 dB – 31.75 dB Attenuation settings	9 KHz ≤ 4 GHz			+ (0.15 + 3% Attenuation Setting) - (0.1 + 1% of Attenuation Setting)	dB	
					+ (0.25 + 5% of Attenuation Setting) 0.0	dB	
	Return loss	Input port	9 kHz – 4 GHz		20		dB
			4 GHz – 6 GHz		15		dB
Return loss	Output port	9 kHz – 4 GHz		17		dB	
		4 GHz – 6 GHz		13		dB	
Relative phase	0 dB – 31.75 dB Attenuation settings	9 kHz – 6 GHz		58		deg	
Input 1dB compression point <sup>1</sup>		50 MHz – 6 GHz	32	34		dBm	
IIP3	Two tones at +18 dBm, 20 MHz spacing	50 MHz – 6 GHz		61		dBm	
Typical spurious value <sup>2</sup>	$V_{SS_{EXT}} = 0V$			-140		dBm	
RF Trise/Tfall	10% / 90% RF			600		ns	
Settling time	RF settled to within 0.05 dB of final value			2		μs	
Switching time	50% CTRL to 90% or 10% RF			1.1		μs	

Notes: 1. The input 1dB compression point is a linearity figure of merit. Refer to *Table 5* for the RF input power  $P_{IN}$  (50Ω)  
 2. To prevent negative voltage generator spurs, supply -3.4 volts to  $V_{SS_{EXT}}$

**Table 2. Electrical Specifications: 0.5 dB steps @ +25°C,  $V_{DD} = 2.3V$  to  $5.5V$ ,  $V_{SS_{EXT}} = 0V$  or  $V_{DD} = 3.4V$  to  $5.5V$ ,  $V_{SS_{EXT}} = -3.4V$  ( $Z_S = Z_L = 50\Omega$ ) unless otherwise noted**

Parameter	Condition	Frequency	Min	Typ	Max	Unit	
Operating frequency			9 kHz		7000 MHz	As shown	
Attenuation range	0.5 dB Step			0 – 31.5		dB	
Insertion loss		9 kHz – 2 GHz		1.3	1.4	dB	
		2 GHz – 4 GHz		1.7	1.9	dB	
		4 GHz – 6 GHz		2.4	2.7	dB	
		6 GHz – 7 GHz		2.5	2.9	dB	
Attenuation error	0 dB – 15.5 dB Attenuation settings	9 KHz ≤ 4 GHz			(0.15 + 3% of Attenuation Setting) - (0.1 + 2% of Attenuation Setting)	dB	
					+ (0.25 + 5% of Attenuation Setting) - 0.25	dB	
	16 dB – 31.5 dB Attenuation settings	9 KHz ≤ 4 GHz			+ (0.15 + 3% of Attenuation Setting) - (0.1 + 2% of Attenuation Setting)	dB	
					+ (0.25 + 6% of Attenuation Setting) - (0.25 + 2.5% of Attenuation Setting)	dB	
	Return loss	Input port	9 kHz – 4 GHz		20		dB
			4 GHz – 7 GHz		16		dB
Return loss	Output port	9 kHz – 4 GHz		17		dB	
		4 GHz – 7 GHz		14		dB	
Relative phase	0 dB – 31.5 dB Attenuation settings	9 kHz – 7 GHz		65		deg	
Input 1dB compression point <sup>1</sup>		50 MHz – 7 GHz	32	34		dBm	
IIP3	Two tones at +18 dBm, 20 MHz spacing	50 MHz – 7 GHz		61		dBm	
Typical spurious value <sup>2</sup>	$V_{SS_{EXT}} = 0V$			-140		dBm	
RF Trise/Tfall	10% / 90% RF			600		ns	
Settling time	RF settled to within 0.05 dB of final value			2		μs	
Switching time	50% CTRL to 90% or 10% RF			1.1		μs	

Notes: 1. The input 1dB compression point is a linearity figure of merit. Refer to *Table 5* for the RF input power  $P_{IN}$  (50Ω)  
2. To prevent negative voltage generator spurs, supply -3.4 volts to  $V_{SS_{EXT}}$

**Table 3. Electrical Specifications: 1 dB steps @ +25°C,  $V_{DD} = 2.3V$  to  $5.5V$ ,  $V_{SS_{EXT}} = 0V$  or  $V_{DD} = 3.4V$  to  $5.5V$ ,  $V_{SS_{EXT}} = -3.4V$  ( $Z_S = Z_L = 50\Omega$ ) unless otherwise noted**

Parameter	Condition	Frequency	Min	Typ	Max	Unit	
Operating frequency			9 kHz		8000 MHz	As shown	
Attenuation range	1 dB Step			0 - 31		dB	
Insertion loss		9 kHz – 2 GHz		1.3	1.4	dB	
		2 GHz – 4 GHz		1.7	1.9	dB	
		4 GHz – 6 GHz		2.4	2.7	dB	
		6 GHz – 8 GHz		2.9	3.2	dB	
Attenuation error	0 dB – 15 dB Attenuation settings	9 kHz $\leq$ 4 GHz			+ (0.15 + 3% of Attenuation Setting) - (0.1 + 1% of Attenuation Setting)	dB dB	
		4 GHz $\leq$ 7 GHz			+ (0.25 + 6% of Attenuation Setting) - (0.25 + 2% of Attenuation Setting)	dB dB	
		7 GHz – 8 GHz			+ (0.25 + 7% of Attenuation Setting) - (0.25 + 2% of Attenuation Setting)	dB dB	
	16dB – 31 dB Attenuation settings	9 kHz $\leq$ 4 GHz				+ (0.15 + 3% of Attenuation Setting) - (0.1 + 1% of Attenuation Setting)	dB dB
		4 GHz $\leq$ 7 GHz				+ (0.25 + 6% of Attenuation Setting) - (0.25 + 3% of Attenuation Setting)	dB dB
		7 GHz – 8 GHz				+ (0.25 + 7% of Attenuation Setting) - (0.25 + 4% of Attenuation Setting)	dB dB
Return loss	Input port	9 kHz – 4 GHz		20		dB	
		4 GHz – 8 GHz		14.5		dB	
Return loss	Output port	9 kHz – 4 GHz		17		dB	
		4 GHz – 8 GHz		12.5		dB	
Relative phase	0 dB – 31 dB Attenuation settings	9 kHz – 8 GHz		80		deg	
Input 1dB compression point <sup>1</sup>		50 MHz – 8 GHz	32	34		dBm	
IIP3	Two tones at +18 dBm, 20 MHz spacing	50 MHz – 8 GHz		61		dBm	
Typical spurious value <sup>2</sup>	$V_{SS_{EXT}} = 0V$			-140		dBm	
RF Trise/Tfall	10% / 90% RF			600		ns	
Settling time	RF settled to within 0.05 dB of final value			2		$\mu$ s	
Switching time	50% CTRL to 90% or 10% RF			1.1		$\mu$ s	

Notes: 1. The input 1dB compression point is a linearity figure of merit. Refer to *Table 5* for the RF input power  $P_{IN}$  (50 $\Omega$ )  
 2. To prevent negative voltage generator spurs, supply -3.4 volts to  $V_{SS_{EXT}}$

Figure 3. Pin Configuration (Top View)

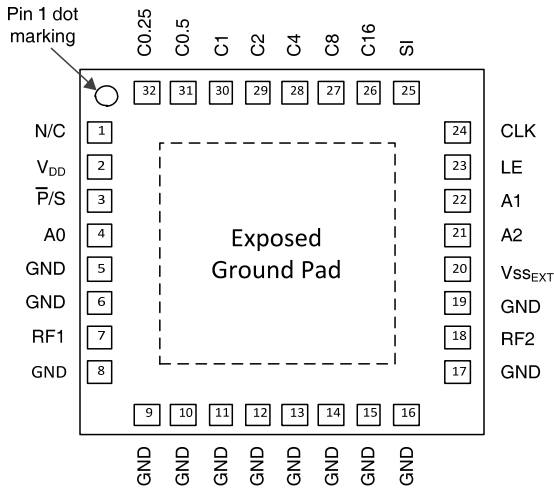


Table 4. Pin Descriptions

Pin #	Pin Name	Description
1	N/C	No connect
2	V <sub>DD</sub>	Supply voltage
3	P/S	Serial/parallel mode select
4	A0	Address bit A0 connection
5, 6, 8-17, 19	GND	Ground
7	RF1 <sup>1</sup>	RF1 port (RF input)
18	RF2 <sup>1</sup>	RF2 port (RF output)
20	V <sub>SS<sub>EXT</sub></sub> <sup>2</sup>	External V <sub>ss</sub> negative voltage control
21	A2	Address bit A2 connection
22	A1	Address bit A1 connection
23	LE	Serial interface latch enable input
24	CLK	Serial interface clock input
25	SI	Serial interface data input
26	C16 (D6) <sup>3</sup>	Parallel control bit, 16 dB
27	C8 (D5) <sup>3</sup>	Parallel control bit, 8 dB
28	C4 (D4) <sup>3</sup>	Parallel control bit, 4 dB
29	C2 (D3) <sup>3</sup>	Parallel control bit, 2 dB
30	C1 (D2) <sup>3</sup>	Parallel control bit, 1 dB
31	C0.5 (D1) <sup>3</sup>	Parallel control bit, 0.5 dB
32	C0.25 (D0) <sup>3</sup>	Parallel control bit, 0.25 dB
Pad	GND	Exposed pad: ground for proper operation

Notes: 1. RF pins 7 and 18 must be at 0V DC. The RF pins do not require DC blocking capacitors for proper operation if the 0V DC requirement is met  
 2. Use V<sub>SS<sub>EXT</sub></sub> (pin 20) to bypass and disable internal negative voltage generator. Connect V<sub>SS<sub>EXT</sub></sub> (pin 20) to GND (V<sub>SS<sub>EXT</sub></sub> = 0V) to enable internal negative voltage generator  
 3. Ground C0.25, C0.5, C1, C2, C4, C8, C16 if not in use

Table 5. Operating Ranges

Parameter	Symbol	Min	Typ	Max	Unit
Supply voltage (normal mode, V <sub>SS<sub>EXT</sub></sub> = 0V) <sup>1</sup>	V <sub>DD</sub>	2.3		5.5	V
Supply voltage (bypass mode, V <sub>SS<sub>EXT</sub></sub> = -3.4V, V <sub>DD</sub> ≥ 3.4V for full spec. compliance) <sup>2</sup>	V <sub>DD</sub>	2.7	3.4	5.5	V
Negative supply voltage (bypass mode) <sup>2</sup>	V <sub>SS<sub>EXT</sub></sub>	-3.6		-2.4	V
Supply current (normal mode, V <sub>SS<sub>EXT</sub></sub> = 0V) <sup>1</sup>	I <sub>DD</sub>		130	200	μA
Supply current (bypass mode, V <sub>SS<sub>EXT</sub></sub> = -3.4V) <sup>2</sup>	I <sub>DD</sub>		50	80	μA
Negative supply current (bypass mode, V <sub>SS<sub>EXT</sub></sub> = -3.4V) <sup>2</sup>	I <sub>SS</sub>	-40	-16		μA
Digital input high	V <sub>IH</sub>	1.17		3.6	V
Digital input low	V <sub>IL</sub>	-0.3		0.6	V
Digital input current	I <sub>CTRL</sub>			15	μA
RF input power, CW <sup>3</sup> 9 kHz < 50 MHz 50 MHz ≤ 8 GHz	P <sub>MAX,CW</sub>			see Fig. 4 +28	dBm
RF input power, pulsed <sup>4</sup> 9 kHz < 50 MHz 50 MHz ≤ 8 GHz	P <sub>MAX,PULSED</sub>			see Fig. 4 +31	dBm
Operating temperature range	T <sub>OP</sub>	-40	25	+85	°C

Notes: 1. Normal mode: connect V<sub>SS<sub>EXT</sub></sub> (pin 20) to GND (V<sub>SS<sub>EXT</sub></sub> = 0V) to enable internal negative voltage generator  
 2. Bypass mode: use V<sub>SS<sub>EXT</sub></sub> (pin 20) to bypass and disable internal negative voltage generator  
 3. 100% duty cycle, all bands, 50Ω  
 4. Pulsed, 5% duty cycle of 4620 μs period, 50Ω

**Table 6. Absolute Maximum Ratings**

Parameter/Condition	Symbol	Min	Max	Unit
Supply voltage	V <sub>DD</sub>	-0.3	5.5	V
Digital input voltage	V <sub>CTRL</sub>	-0.3	3.6	V
RF input power, max	P <sub>MAX,ABS</sub>		+34	dBm
Storage temperature range	T <sub>ST</sub>	-65	+150	°C
ESD voltage HBM <sup>1</sup> , all pins	V <sub>ESD,HBM</sub>		1500	V
ESD voltage MM <sup>2</sup> , all pins	V <sub>ESD,MM</sub>		200	V
ESD voltage CDM <sup>3</sup> , all pins	V <sub>ESD,CDM</sub>		250	V

Notes: 1. Human Body Model (MIL-STD 883 Method 3015)  
2. Machine Model (JEDEC JESD22-A115)  
3. Charged Device Model (JEDEC JESD22-C101)

Exceeding absolute maximum ratings may cause permanent damage. Operation should be restricted to the limits in the Operating Ranges table. Operation between operating range maximum and absolute maximum for extended periods may reduce reliability.

### Electrostatic Discharge (ESD) Precautions

When handling this UltraCMOS<sup>®</sup> device, observe the same precautions that you would use with other ESD-sensitive devices. Although this device contains circuitry to protect it from damage due to ESD, precautions should be taken to avoid exceeding the specified rating.

### Latch-Up Avoidance

Unlike conventional CMOS devices, UltraCMOS<sup>®</sup> devices are immune to latch-up.

### Moisture Sensitivity Level

The Moisture Sensitivity Level rating for the PE43704 in the 5x5 QFN package is MSL1.

### Switching Frequency

The PE43704 has a maximum 25 kHz switching rate when the internal negative voltage generator is used (pin 20 = GND). The rate at which the PE43704 can be switched is only limited to the switching time (*Tables 1-3*) if an external negative supply is provided (pin 20 = V<sub>SS,EXT</sub>).

Switching frequency is defined to be the speed at which the DSA can be toggled across attenuation states. Switching time is the time duration between the point the control signal reaches 50% of the final value and the point the output signal reaches within 10% or 90% of its target value.

### Optional External V<sub>SS</sub> Control (V<sub>SS,EXT</sub>)

For proper operation, the V<sub>SS,EXT</sub> control pin must be grounded or tied to the V<sub>SS</sub> voltage specified in *Table 5*. When the V<sub>SS,EXT</sub> control pin is grounded, FETs in the switch are biased with an internal voltage generator. For applications that require the lowest possible spur performance, V<sub>SS,EXT</sub> can be applied externally to bypass the internal negative voltage generator.

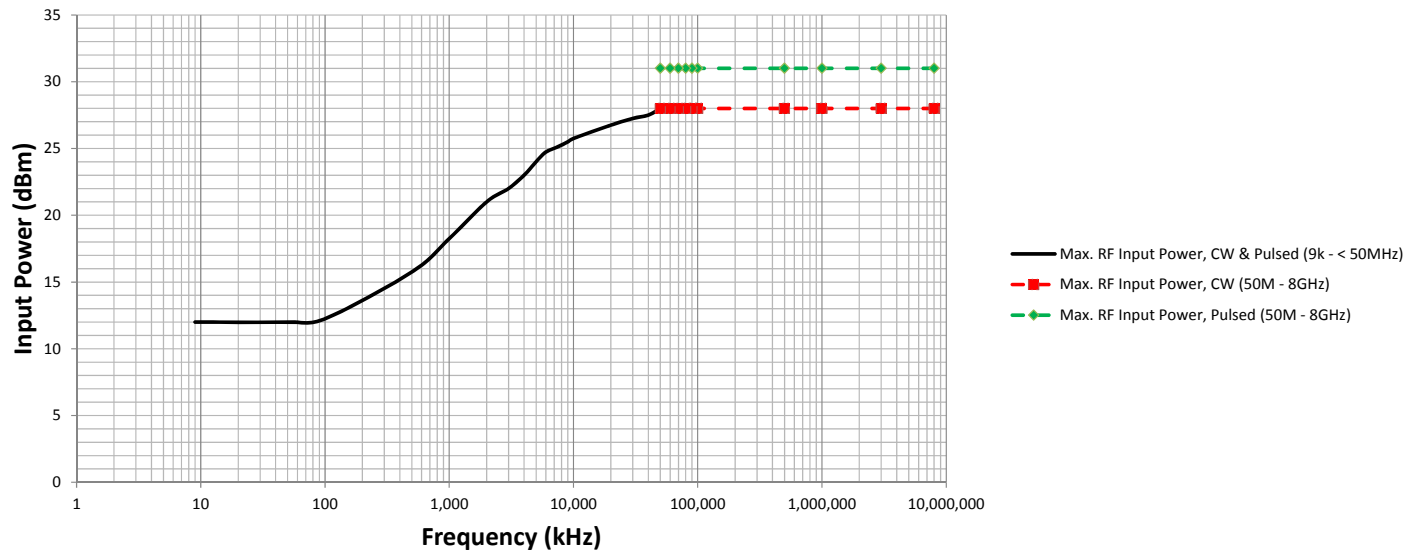
**Table 7. Latch and Clock Specifications**

Latch Enable	Shift Clock	Function
0	↑	Shift register clocked
↑	X	Contents of shift register transferred to attenuator core

### Safe Attenuation State Transitions

The PE43704 features a novel architecture to provide safe transition behavior when changing attenuation states. When RF input power is applied, positive output power spikes are prevented during attenuation state changes by optimized internal timing control.

Figure 4. Power De-rating Curve (50Ω, -40°C to 85°C Ambient)







## Programming Options

### Parallel/Serial Selection

Either a parallel or serial-addressable interface can be used to control the PE43704. The  $\bar{P}/S$  bit provides this selection, with  $\bar{P}/S = \text{LOW}$  selecting the parallel interface and  $\bar{P}/S = \text{HIGH}$  selecting the serial-addressable interface.

### Parallel Mode Interface

The parallel interface consists of seven CMOS-compatible control lines that select the desired attenuation state, as shown in *Table 8*.

The parallel interface timing requirements are defined by *Figure 6* (Parallel Interface Timing Diagram), *Table 13* (Parallel and Direct Interface AC Characteristics) and switching time (*Tables 1-3*).

For *latched*-parallel programming the Latch Enable (LE) should be held LOW while changing attenuation state control values, then pulse LE HIGH to LOW (*per Figure 6*) to latch new attenuation state into device.

For *direct* parallel programming, the Latch Enable (LE) line should be pulled HIGH. Changing attenuation state control values will change device state to new attenuation. Direct mode is ideal for manual control of the device (using hardware, switches, or jumpers).

### Serial Interface

The serial-addressable interface is a 16-bit serial-in, parallel-out shift register buffered by a transparent latch. The 16-bits make up two words comprised of 8-bits each. The first word is the Attenuation Word, which controls the state of the DSA. The second word is the Address Word, which is compared to the static (or programmed) logical states of the A0, A1 and A2 digital inputs. If there is an address match, the DSA changes state; otherwise its current state will remain unchanged. *Figure 5* illustrates an example timing diagram for programming a state. It is required that all parallel control inputs be grounded when the DSA is used in serial-addressable mode.

The serial-interface is controlled using three CMOS-compatible signals: Serial-In (SI), Clock (CLK), and Latch Enable (LE). The SI and CLK inputs allow data to be serially entered into the shift register. Serial data is clocked in LSB first, beginning with the Attenuation Word.

The shift register must be loaded while LE is held LOW to prevent the attenuator value from changing as data is entered. The LE input should then be toggled HIGH and brought LOW again, latching the new data into the DSA. Attenuation Word and Address Word truth tables are listed in *Table 9* and *Table 10*. A programming example of the serial register is illustrated in *Table 11*. The serial timing diagram is illustrated in *Figure 5*.

### Power-up Control Settings

The PE43704 will always initialize to the maximum attenuation setting (31.75 dB) on power-up for both the serial-addressable and latched-parallel modes of operation and will remain in this setting until the user latches in the next programming word. In direct-parallel mode, the DSA can be preset to any state within the 31.75 dB range by pre-setting the parallel control pins prior to power-up. In this mode, there is a 400- $\mu\text{s}$  delay between the time the DSA is powered-up to the time the desired state is set. During this power-up delay, the device attenuates to the maximum attenuation setting (31.75 dB) before defaulting to the user defined state. If the control pins are left floating in this mode during power-up, the device will default to the minimum attenuation setting (insertion loss state).

Dynamic operation between serial and parallel programming modes is possible.

If the DSA powers up in serial mode ( $\bar{P}/S = \text{HIGH}$ ), all the parallel control inputs DI[6:0] must be set to logic low. Prior to toggling to parallel mode, the DSA *must* be programmed serially to ensure D[7] is set to logic low.

If the DSA powers up in either latched or direct-parallel mode, all parallel pins DI[6:0] must be set to logic low prior to toggling to serial-addressable mode ( $\bar{P}/S = \text{HIGH}$ ), and *held* low until the DSA has been programmed serially to ensure bit D[7] is set to logic low.

The sequencing is only required once on power-up. Once completed, the DSA may be toggled between serial and parallel programming modes at will.

Figure 5. Serial Timing Diagram

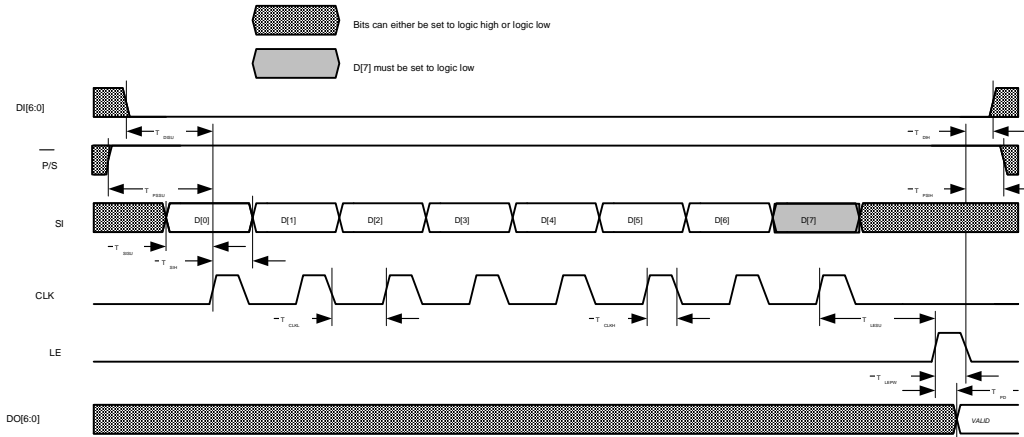


Figure 6. Latched-Parallel/Direct-Parallel Timing Diagram

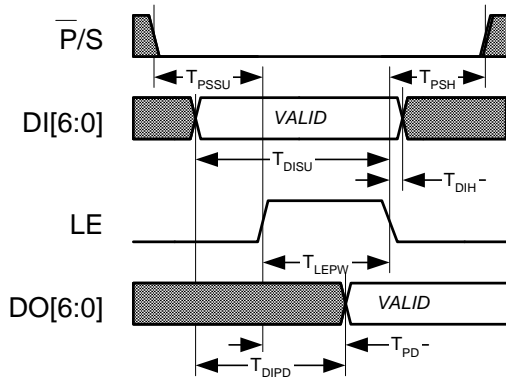


Table 12. Serial Interface AC Characteristics

$V_{DD} = 3.4V$  or  $5.0V$ ,  $-40^{\circ}C < T_A < 85^{\circ}C$ , unless otherwise specified

Parameter	Symbol	Min	Max	Unit
Serial clock frequency	$F_{CLK}$	-	10	MHz
Serial clock HIGH time	$T_{CLKH}$	30	-	ns
Serial clock LOW time	$T_{CLKL}$	30	-	ns
Last serial clock rising edge setup time to Latch Enable rising edge	$T_{LESU}$	10	-	ns
Latch enable min. pulse width	$T_{LEPW}$	30	-	ns
Serial data setup time	$T_{SISU}$	10	-	ns
Serial data hold time	$T_{SIH}$	10	-	ns
Parallel data setup time	$T_{DISU}$	100	-	ns
Parallel data hold time	$T_{DIH}$	100	-	ns
Address setup time	$T_{ASU}$	100	-	ns
Address hold time	$T_{AH}$	100	-	ns
Parallel/serial setup time	$T_{PSSU}$	100	-	ns
Parallel/serial hold time	$T_{PSH}$	100	-	ns
Digital register delay (internal)	$T_{PD}$	-	10	ns

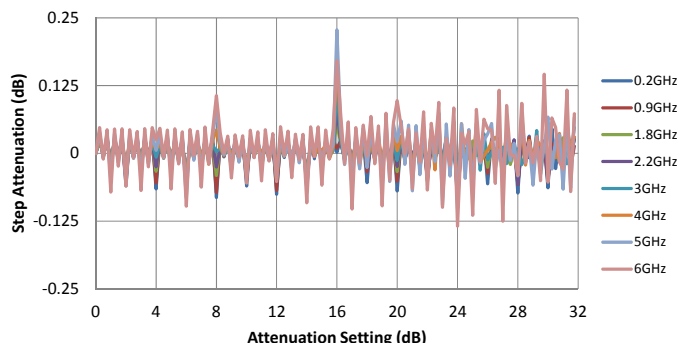
Table 13. Parallel and Direct Interface AC Characteristics

$V_{DD} = 3.4V$  or  $5.0V$ ,  $-40^{\circ}C < T_A < 85^{\circ}C$ , unless otherwise specified

Symbol	Parameter	Min	Max	Unit
$T_{LEPW}$	Latch enable minimum pulse width	30	-	ns
$T_{DISU}$	Parallel data setup time	100	-	ns
$T_{DIH}$	Parallel data hold time	100	-	ns
$T_{PSSU}$	Parallel/serial setup time	100	-	ns
$T_{PSH}$	Parallel/serial hold time	100	-	ns
$T_{PD}$	Digital register delay (internal)	-	10	ns
$T_{DIPD}$	Digital register delay (internal, direct mode only)	-	5	ns

Typical Performance Data, 0.25 dB Step @ 25°C and  $V_{DD} = 3.4V$  unless otherwise specified

Figure 7. 0.25 dB Step Attenuation vs. Frequency\*



\* Monotonicity is held so long as step-attenuation does not cross below -0.25 dB

Figure 8. 0.25 dB Step, Actual vs. Frequency

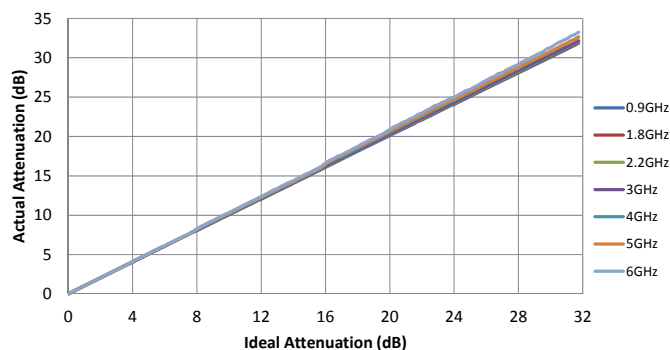


Figure 9. 0.25 dB Major State Bit Error vs. Attenuation Setting

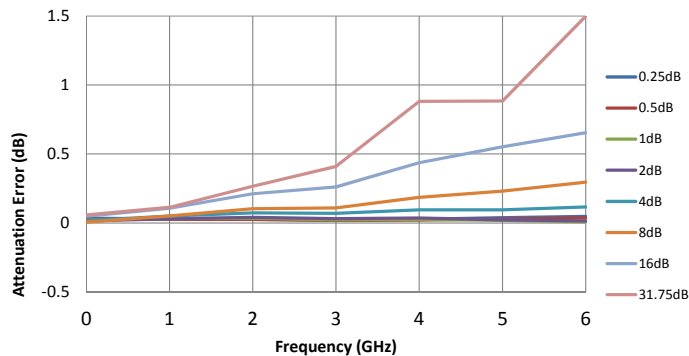
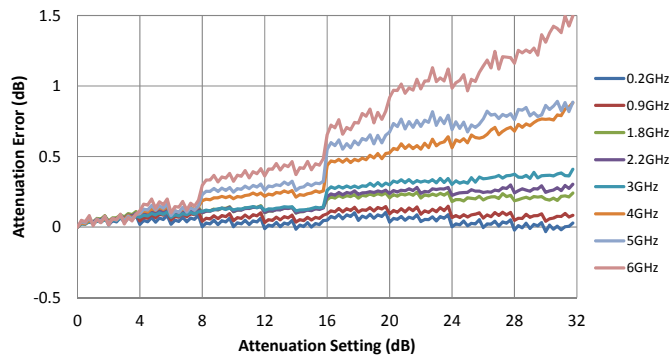
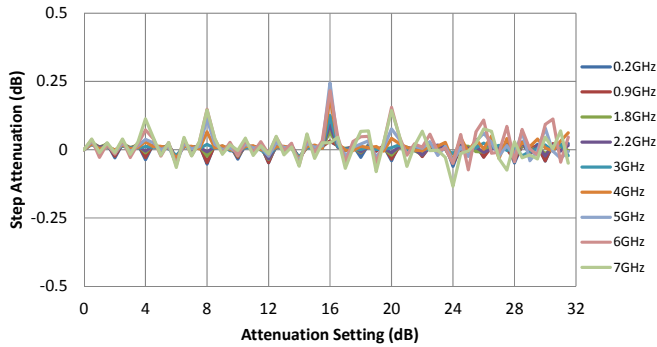


Figure 10. 0.25 dB Attenuation Error vs. Frequency



Typical Performance Data, 0.5 dB Step @ 25°C and  $V_{DD} = 3.4V$  unless otherwise specified

Figure 11. 0.5 dB Step Attenuation vs. Frequency\*



\* Monotonicity is held so long as step-attenuation does not cross below -0.5 dB

Figure 12. 0.5 dB Step, Actual vs. Frequency

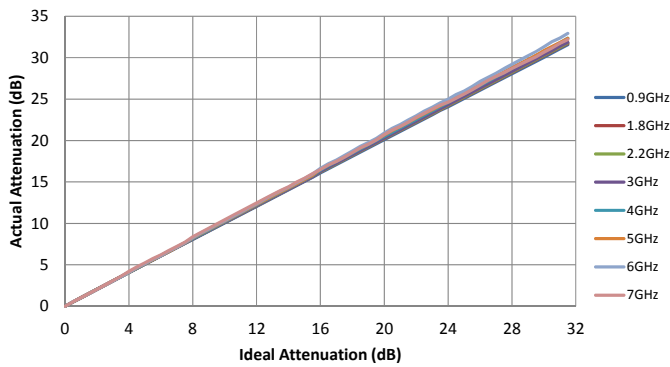


Figure 13. 0.5 dB Major State Bit Error vs. Attenuation Setting

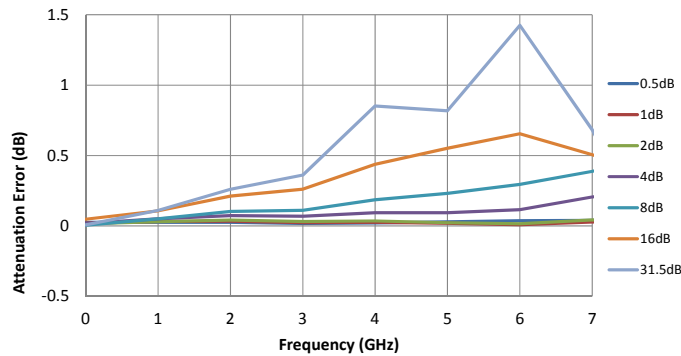
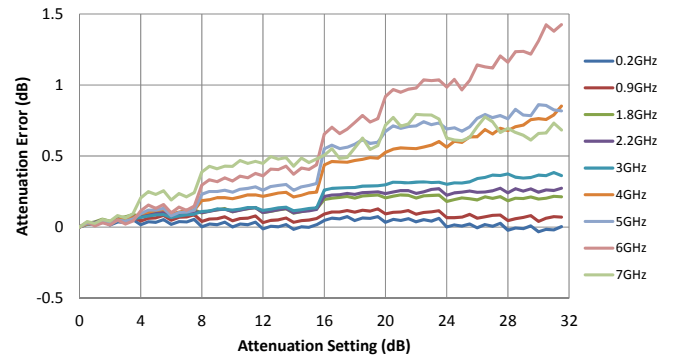
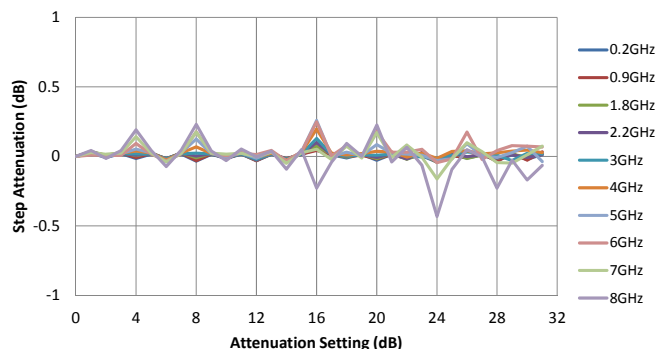


Figure 14. 0.5 dB Attenuation Error vs. Frequency



Typical Performance Data, 1 dB Step @ 25°C and  $V_{DD} = 3.4V$  unless otherwise specified

Figure 15. 1 dB Step Attenuation vs. Frequency\*



\* Monotonicity is held so long as step-attenuation does not cross below -1.0 dB

Figure 16. 1 dB Step, Actual vs. Frequency

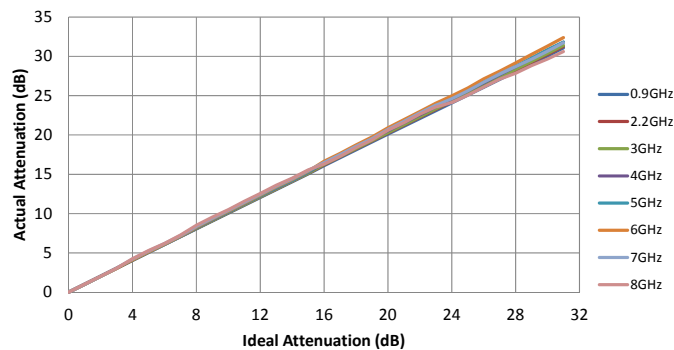
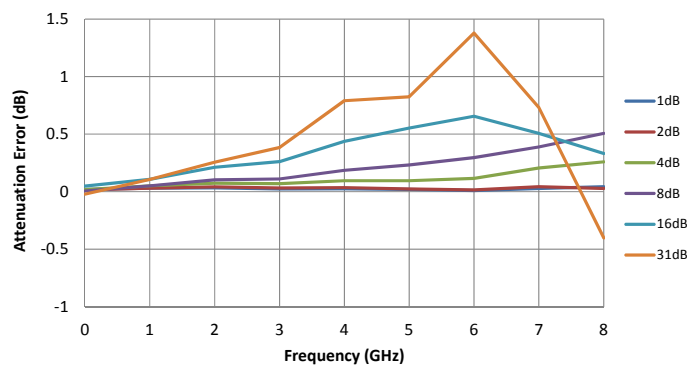


Figure 17. 1 dB Major State Bit Error vs. Attenuation Setting



Typical Performance Data, 1 dB Step @ 25°C and  $V_{DD} = 3.4V$  unless otherwise specified

Figure 18. 1 dB Attenuation Error vs. Frequency

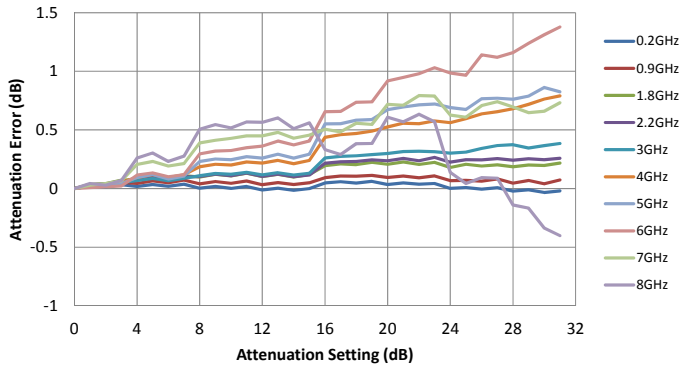


Figure 19. Insertion Loss vs. Temperature

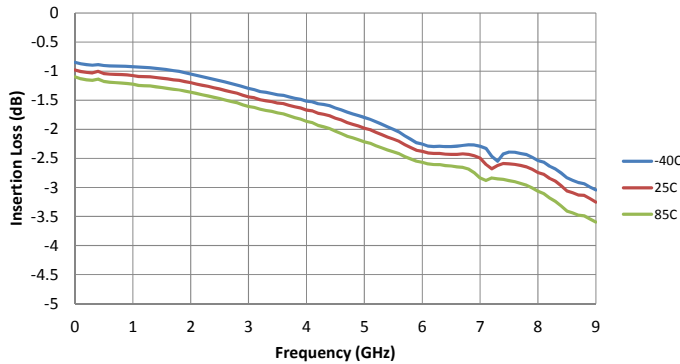


Figure 20. Input Return Loss vs. Attenuation Setting

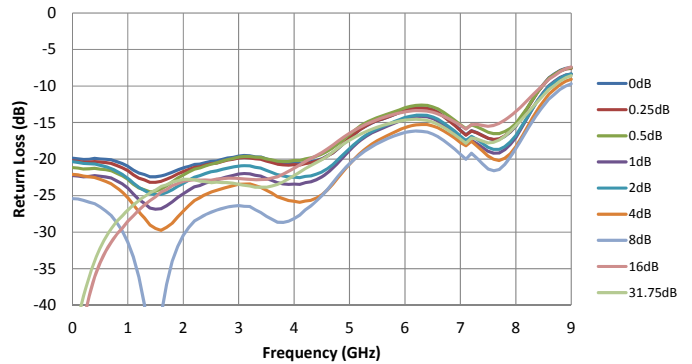
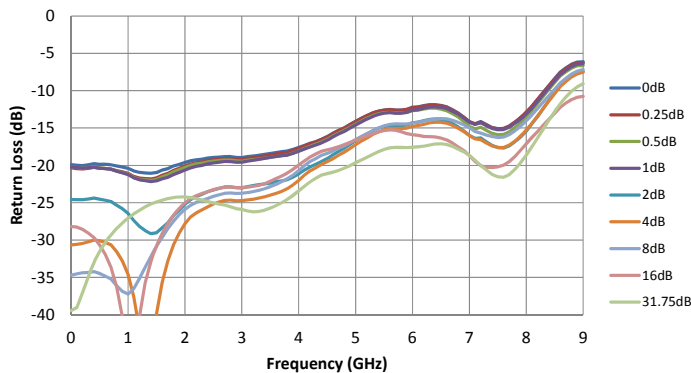


Figure 21. Output Return Loss vs. Attenuation Setting



Typical Performance Data, 1 dB Step @ 25°C and  $V_{DD} = 3.4V$  unless otherwise specified

Figure 22. Input Return Loss vs. Temperature for 16 dB Attenuation Setting

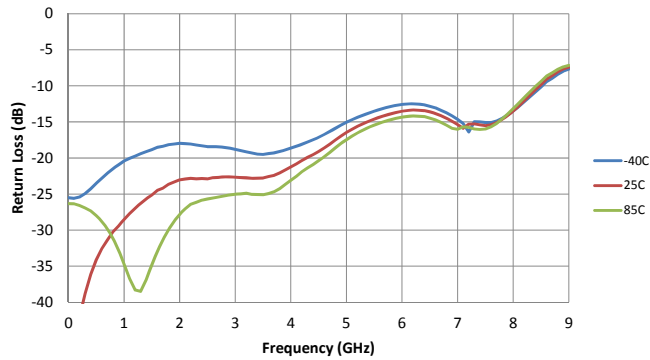
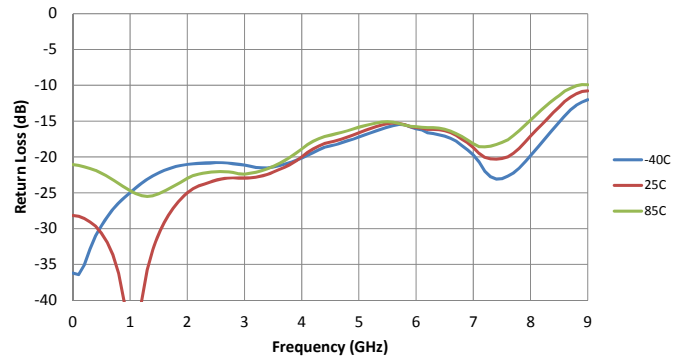


Figure 23. Output Return Loss vs. Temperature for 16 dB Attenuation Setting



Typical Performance Data @ 25°C and V<sub>DD</sub> = 3.4V unless otherwise specified

Figure 24. Relative Phase Error vs. Attenuation Setting

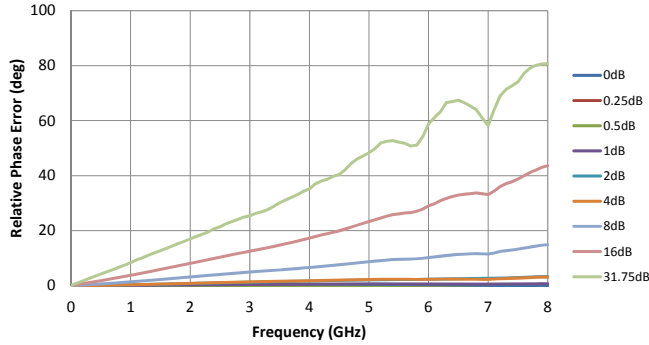


Figure 25. Relative Phase Error for 31.75 dB Attenuation Setting vs. Frequency

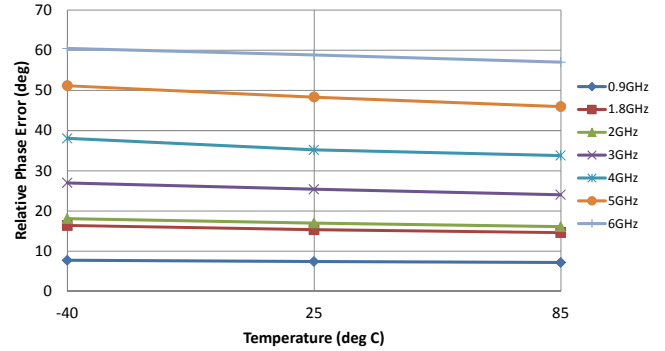


Figure 26. Attenuation Error @ 900 MHz vs. Temperature

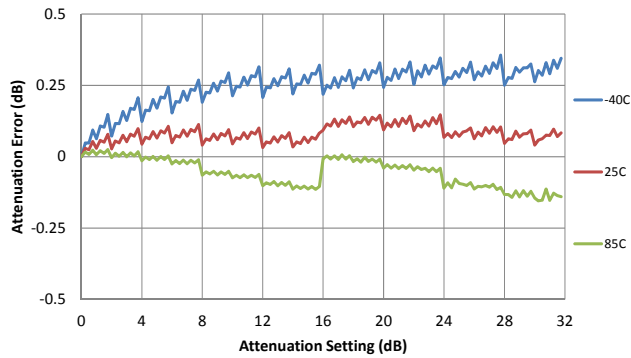


Figure 27. Attenuation Error @ 1800 MHz vs. Temperature

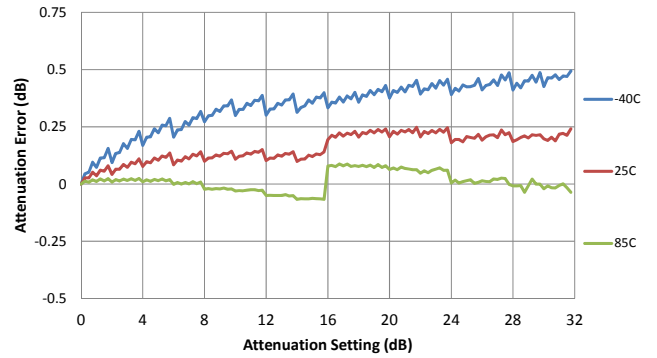


Figure 28. Attenuation Error @ 3000 MHz vs. Temperature

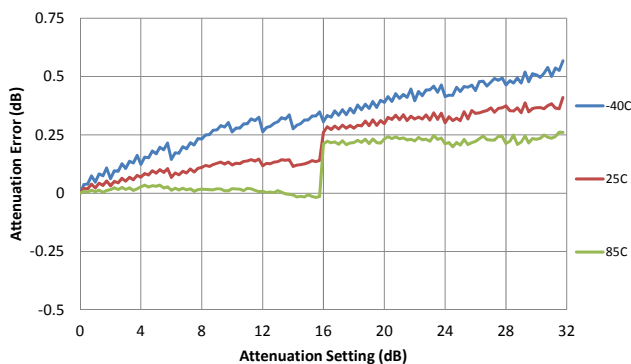
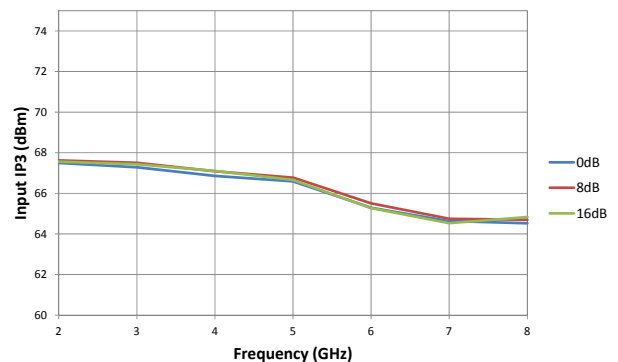


Figure 29. IIP3 vs. Attenuation Setting





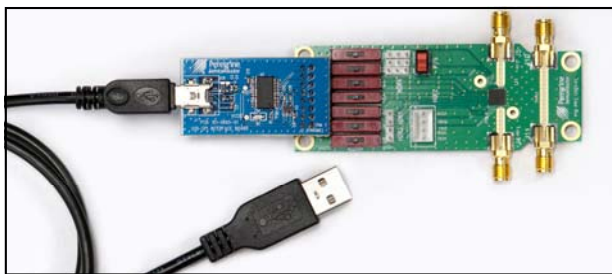
## Evaluation Kit

The Digital Attenuator Evaluation Board (EVB) was designed to ease customer evaluation of the PE43704 Digital Step Attenuator. PE43704 EVB supports direct-parallel, latched-parallel, and serial modes.

### Evaluation Kit Setup

Connect the EVB with the USB dongle board and USB cable as shown in *Figure 30*.

**Figure 30. Evaluation Kit**



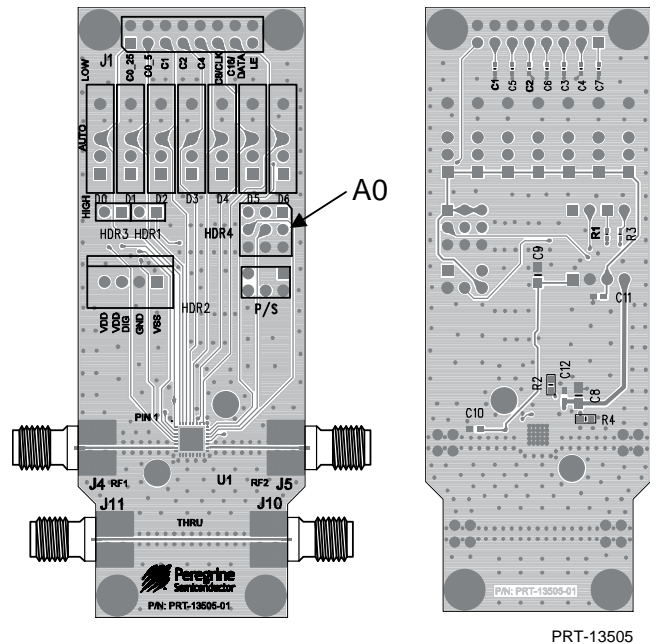
### Direct-Parallel Programming Procedure

Direct-parallel programming is suitable for manual operation without software programming. For manual direct-parallel programming, position the Parallel/Serial (P/S) select switch to the Parallel (or left) position. The LE pin of J1 (pin 15) must be tied to HIGH voltage. Switches D0–D6 are SP3T switches that enable the user to manually program the parallel bits. When D0–D6 are toggled to the ‘HIGH’ position, logic high is presented to the parallel input. When toggled to the ‘LOW’ position, logic low is presented to the parallel input. Setting D0–D6 to the ‘AUTO’ position presents as OPEN, which is set for software programming of Latched-Parallel and Serial mode. *Table 8* depicts the parallel programming truth table.

### Latched-Parallel Programming Procedure

For automated latched-parallel programming, connect the USB dongle board and cable that is provided with the Evaluation Kit (EVK) from the USB port of the PC to the J1 header of the PE43704 EVB, and set the D0–D6 SP3T switches to the ‘AUTO’ position. Position the Parallel/Serial (P/S) select switch to the Parallel (or left) position. The evaluation software is written to operate the

**Figure 31. Evaluation Board Layout**



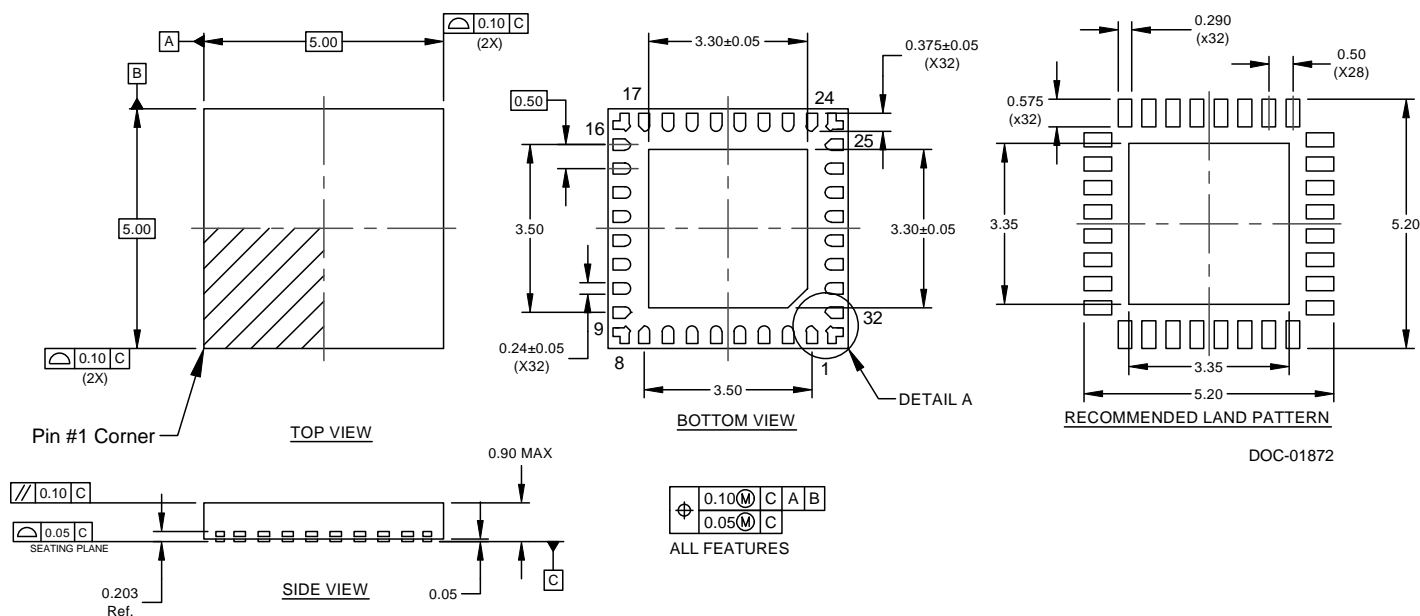
DSA in Parallel Mode. Ensure that the software GUI is set to Latched-Parallel mode. Use the software GUI to enable the desired attenuation state. The software GUI automatically programs the DSA each time an attenuation state is enabled.

### Serial-Addressable Programming Procedure

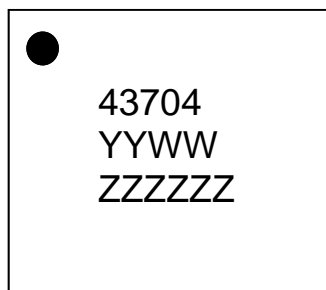
For automated serial programming, connect the USB dongle board and cable that is provided with the Evaluation Kit (EVK) from the USB port of the PC to the J1 header of the PE43704 EVB, and set the D0–D6 SP3T switches to the ‘AUTO’ toggle position. Position the Parallel/Serial (P/S) select switch to the Serial (or right) position. Prior to programming, the user must define an address setting using the HDR4 header pin. Jump the middle row of pins on the HDR4 header (A0–A2) to the lower row of pins to set logic low, or jump the middle row of pins to the upper row of pins to set logic high. If the HDR4 pins are left open, then 000 becomes the default address. The software GUI is written to operate the DSA in Serial mode. Use the software GUI to enable each setting to the desired attenuation state. The software GUI automatically programs the DSA each time an attenuation state is enabled.



**Figure 33. Package Drawing**  
32-lead 5x5 QFN



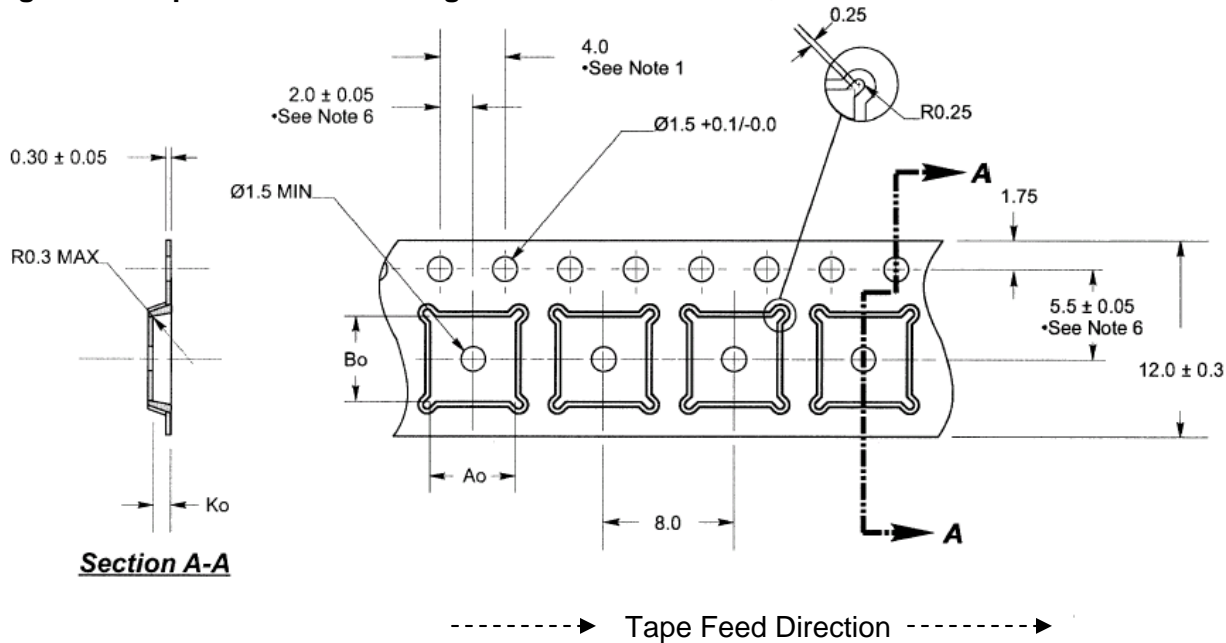
**Figure 34. Top Marking Specification**



17-0091

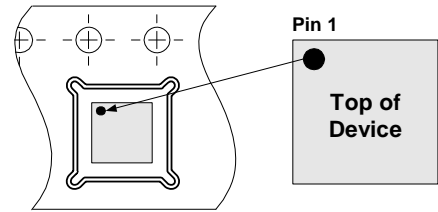
- = Pin 1 designator
- YYWW = Date Code, last two digits of the year and work week
- ZZZZZZ = Six digits of the lot number

**Figure 35. Tape and Reel Drawing**



- Notes:
1. 10 sprocket hole pitch cumulative tolerance  $\pm 0.02$
  2. Camber not to exceed 1 mm in 100 mm
  3. Material: PS + C
  4.  $A_o$  and  $B_o$  measured as indicated
  5.  $K_o$  measured from a plane on the inside bottom of the pocket to the top surface of the carrier
  6. Pocket position relative to sprocket hole measured as true position of pocket, not pocket hole

$A_o = 5.25$  mm  
 $B_o = 5.25$  mm  
 $K_o = 1.1$  mm



Device Orientation in Tape

**Table 14. Ordering Information**

Order Code	Description	Package	Shipping Method
PE43704MLCA-Z	PE43704 Digital step attenuator	32-lead 5x5 mm QFN	3000 units / T&R
EK43704-11	PE43704 Evaluation kit	Evaluation kit	1 / Box

**Sales Contact and Information**

For sales and contact information please visit [www.psemi.com](http://www.psemi.com).

**Advance Information:** The product is in a formative or design stage. The datasheet contains design target specifications for product development. Specifications and features may change in any manner without notice.  
**Preliminary Specification:** The datasheet contains preliminary data. Additional data may be added at a later date. Peregrine reserves the right to change specifications at any time without notice in order to supply the best possible product.  
**Product Specification:** The datasheet contains final data. In the event Peregrine decides to change the specifications, Peregrine will notify customers of the intended changes by issuing a CNF (Customer Notification Form).  
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